# NSN 5961-01-236-8268

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## Inclosure Material:

Metal

**Overall Length:** 

0.210 inches

# Terminal Length:

0.750 inches

# **Overall Diameter:**

0.230 inches

### Internal Configuration:

Field effect

# Joint Electronic Device Engineering Council/jedec/case Outline Designation:

#### To-18

Electrode Internally-electrically Connected To Case:

#### Gate

**Mounting Method:** 

#### would

Terminal

# Terminal Circle Diameter:

0.100 inches

#### **Features Provided:**

Hermetically sealed case and quality assurance level s

#### Semiconductor Material:

Silicon

#### Voltage Rating In Volts Per Characteristic:

-40.0 drain to gate voltage and 40.0 drain to source voltage and 40.0 gate to source voltage

#### **Current Rating Per Characteristic:**

50.00 milliamperes gate current

#### Power Rating Per Characteristic:

1.8 watts total power dissipation

#### Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

#### Test Data Document:

81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

#### Terminal Type And Quantity:

3 uninsulated wire lead

#### **Specification Data:**

81349-mil-s-19500/385 government specification

#### Shelf Life:

N/a

#### Unit Of Measure:

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Demilitarization:

No

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